

v00.0910

RoHS EARTH PRIE

Typical Applications

The HMC973LP3E is ideal for:

- Point-to-Point Radio
- Cellular/3G & WiMAX/4G Infrastructure
- Test Instrumentation
- Microwave Sensors
- Military, ECM & Radar

Functional Diagram



GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, 0.5 - 6.0 GHz

HMC973LP3E

Features

Excellent Linearity: +35 dBm Input IP3 Wide Attenuation Range: 26 dB Single Positive Voltage Control: 0 to +5V Absorptive Topology 16 Lead 3x3mm SMT Package: 9mm²

General Description

The HMC973LP3E is an absorptive Voltage Variable Attenuator (VVA) which operates from 0.5 to 6 GHz and is ideal in designs where an analog DC control signal must be used to control RF signal levels over a 26 dB amplitude range. It features a shunt-type attenuator controlled by an analog voltage, Vctrl. Unlike other GaAs FET based VVA's the HMC973LP3E exhibits excellent linearity of +35 dBm input IP3, throughout it's control range. The HMC973LP3E is an unidirectional device with optimum linearity performance achieved when the RF input signal is applied to the RFIN package lead. The HMC973LP3E is housed in a RoHS compliant 3x3 mm QFN leadless package.

Electrical Specifications, $T_A = +25^{\circ}$ C, 50 Ohm system, Vdd = +5V

Parameter	Frequency	Min.	Тур.	Max.	Units
Insertion Loss	0.5 - 4.0 GHz 4.0 - 6.0 GHz		3.5 5.5	5 8	dB dB
Attenuation Range	0.5 - 3.0 GHz 3.0 - 6.0 GHz		26 28		dB
Input Return Loss	0.5 - 6.0 GHz		12		dB
Output Return Loss	0.5 - 6.0 GHz		10		dB
Input Power for 1 dB Compression (any attenuation)	0.5 - 6.0 GHz		30		dBm
Input Third Order Intercept (Two-tone Input Power = +5 dBm Each Tone)	0.5 - 6.0 GHz		35		dBm
Supply Current (Idd)	0.5 - 6.0 GHz		200	300	μA

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Insertion Loss vs. Frequency Over Temperature



Attenuation vs. Vctrl Over Temperature @ 0.5 GHz









Attenuation vs. Frequency Over Vctrl



Attenuation vs. Vctrl Over Temperature @ 2 GHz



Attenuation vs. Vctrl Over Temperature @ 6 GHz



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Output Return Loss Over Temperature (Vctrl = 0)



Input IP3 Over Vctrl







Output Return Loss Over Vctrl



Input IP3 Over Temperature (Vctrl = 0V)



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Absolute Maximum Ratings

RF Input Power	+29 dBm
Vdd	5.5V
Control Voltage Range	-0.5 to 5.5V
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C)	0.8W
Thermal Resistance (Channel to ground paddle)	80 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

3.10 2.90

13

8

12

q

.122

.114

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HMC PART

(DIGITS ONLY)

NUMBER

3.10

2.90

Voltages & Currents



8

Outline Drawing

Δ

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NOTES

- 1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC SILICA AND SILICON IMPREGNATED.
- 2. LEAD AND GROUND PADDLE MATERIAL: COPPER ALLOY.
- 3. LEAD AND GROUND PADDLE PLATING: 100% MATTE TIN.
- 4. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 5. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 6. PAD BURR LENGTH SHALL BE 0.15mm MAX.
- PAD BURR HEIGHT SHALL BE 0.05mm MAX.
- 7. PACKAGE WARP SHALL NOT EXCEED 0.05mm
- 8. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND
- 9. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[1]
HMC973LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>H973</u> XXXX
[1] 4-Digit lot number	XXXX			

[2] Max peak reflow temperature of 260 °C

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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 2, 4, 9, 11, 12 Ground Paddle	GND	These pins and the exposed ground paddle must be connected to RF/DC ground.	
3	RFOUT	This pin is DC coupled and matched to 50 Ohms. A blocking capacitor is required if RF line potential is not equal to 0V.	ESD
5	Vdd	Supply Voltage	
6, 8, 13 - 16	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
7	Vctrl	Control Voltage	Vctrl ESD =
10	RFIN	This pin is DC coupled and matched to 50 Ohms. A blocking capacitor is required if RF line potential is not equal to 0V. The HMC973LP3E is a unidirectional device with optimum linearity performance achieved with RF input signal applied to RFIN package lead.	



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Evaluation PCB



List of Materials for Evaluation PCB 131552 [1]

Item	Description	
J1, J2	PCB Mount SMA RF Connector	
J3 - J5	DC Pin	
C1, C2	100 pF Capacitor, 0402 Pkg.	
C3, C4	10000 pF Capacitor, 0402 Pkg.	
U1	HMC973LP3E Voltage Variable Attenuator	
PCB ^[2]	131550 Evaluation PCB	

[1] Reference this number when ordering complete evaluation PCB[2] Circuit Board Material: Arlon 25FR or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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